

# STPS60SM200C

## Power Schottky rectifier

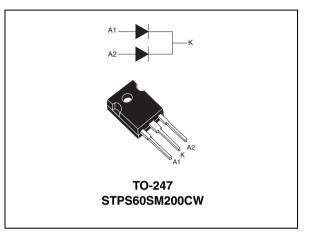
### Features

- High reverse voltage (200 V)
- Low forward voltage drop
- High frequency operation

### Description

The STPS60SM200C is a dual Schottky rectifier suited for high frequency switched-mode power supply.

Housed in TO-247, this device is especially suited for use in telecom base station SMPS, providing these applications with a good efficiency at both low and high load.



Symbol	Value		
I <sub>F(AV)</sub>	2 x 30 A		
V <sub>RRM</sub>	200 V		
T <sub>j</sub> (max)	175 °C		
V <sub>F</sub> (typ)	640 mV		

## 1 Characteristics

#### Table 2. Absolute ratings (limiting values per diode at 25 °C, unless otherwise specified)

Pa	Value	Unit			
Repetitive peak reverse voltage			200	V	
Forward current rms			50	А	
Average forward surrent $\delta = 0.5$	Per diode, $\delta = 0.5$	T <sub>c</sub> = 155 °C	30	۸	
$I_{F(AV)}$ Average forward current $\delta = 0.5$	per device, $\delta = 0.5$	T <sub>c</sub> = 150 °C	60	A	
Surge non repetitive forward current	t <sub>p</sub> = 10 ms sinusoida	al, $T_c = 25 \ ^{\circ}C$	500	А	
Storage temperature range -65 to + 175				°C	
Maximum operating junction temperature <sup>(1)</sup> -40 to + 175			°C		
	Repetitive peak reverse voltage Forward current rms Average forward current $\delta = 0.5$ Surge non repetitive forward current Storage temperature range	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	Repetitive peak reverse voltageForward current rmsAverage forward current $\delta = 0.5$ Per diode, $\delta = 0.5$ $T_c = 155 \degree C$ per device, $\delta = 0.5$ $T_c = 150 \degree C$ Surge non repetitive forward current $t_p = 10 \mbox{ ms sinusoidal, } T_c = 25 \degree C$ Storage temperature range	Repetitive peak reverse voltage200Forward current rms50Average forward current $\delta = 0.5$ Per diode, $\delta = 0.5$ $T_c = 155 \text{ °C}$ 30Average forward current $\delta = 0.5$ $per device, \delta = 0.5$ $T_c = 150 \text{ °C}$ 60Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}, T_c = 25 \text{ °C}$ 500Storage temperature range-65 to + 175	

 $1. \quad \frac{dPtot}{dTj} < \frac{1}{Rth(j-a)} \text{ condition to avoid thermal runaway for a diode on its own heatsink}$ 

#### Table 3. Thermal resistance

Symbol	Parameter		Value	Unit
P	Junction to case	Per diode	0.7	
R <sub>th(j-c)</sub>	Sunction to case	Total	0.5	°C/W
R <sub>th(c)</sub>	Coupling		0.3	

When the two diodes 1 and 2 are used simultaneously:

 $\Delta T_{j}$ (diode 1) = P(diode 1) x R<sub>th(j-c)</sub>(Per diode) + P(diode 2) x R<sub>th(c)</sub>

#### Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
ا <sub>B</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	V V			0.05	mA
'R`	R <sup>*</sup> Heverse leakage current	T <sub>j</sub> = 125 °C	$V_{R} = V_{RRM}$		6	13	ma
	$V_{F}^{(2)} Forward voltage drop \qquad \qquad \begin{array}{c} T_{j} = 12 \\ T_{j} = 25 \\ T_{j} = 12 \end{array}$	$T_j = 25 \text{ °C}$ $I_F = 7.5 \text{ A}$		0.67	0.70		
		T <sub>j</sub> = 125 °C	$I_{\rm F} = 7.5 {\rm A}$		0.51	0.55	
V (2)		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 15 A		0.73	0.77	V
۷F		T <sub>j</sub> = 125 °C	F = 15 A		0.57	0.61	v
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 30 A		0.79	0.83	
		T <sub>j</sub> = 125 °C	F = 30 A		0.64	0.69	

1. Pulse test:  $t_p = 5 \text{ ms}, \delta < 2\%$ 

2. Pulse test:  $t_p = 380 \ \mu s, \ \delta < 2\%$ 

To evaluate the conduction losses use the following equation:

 $P = 0.58 \text{ x } I_{F(AV)} + 0.0037 \text{ x } I_{F}^{2}(RMS)$ 



Figure 1. Average forward power dissipation Figure 2. versus average forward current (per diode)

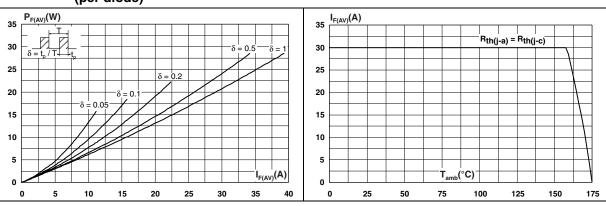


Figure 3. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

Figure 4. Relative variation of thermal impedance junction to case versus pulse duration

Average forward current versus

ambient temperature ( $\delta = 0.5$ )

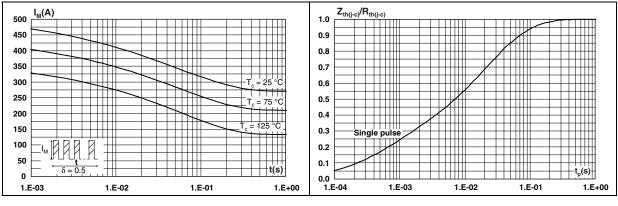
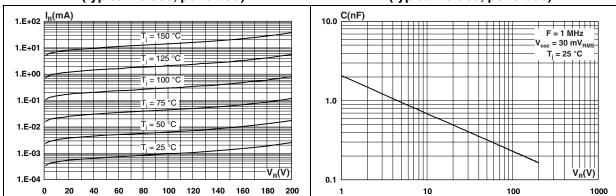


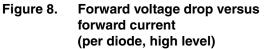
Figure 5. Reverse leakage current versus reverse voltage applied (typical values, per diode)

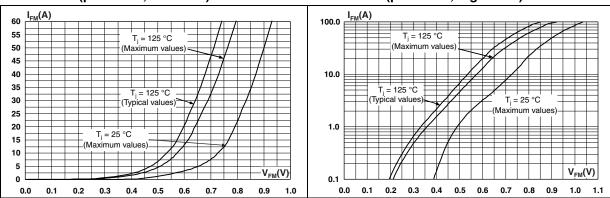
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Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode)



#### Figure 7. Forward voltage drop versus forward current (per diode, low level)







## 2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 to 1.0 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK<sup>®</sup> is an ST trademark.

Table 5. TO-247 dimensions

				Dimensions			
	Ref.	Millin	neters	Inc	hes		
		Min.	Max.	Min.	Max.		
	Α	4.85	5.16	0.191	0.203		
	D	2.20	2.60	0.086	0.102		
	Е	0.40	0.80	0.015	0.031		
V Dia	F	1.00	1.40	0.039	0.055		
	F1	3.00	typ.	0.118	3 typ.		
H A	F2	2.00	) typ.	0.079	9 typ.		
	F3	1.90	2.40	0.075	0.094		
	F4	3.00	3.40	0.118	0.134		
	G	10.90 typ.		0.429 typ.			
	Н	15.45	16.03	0.608	0.631		
	L	19.85	21.09	0.781	0.830		
$F1 \xrightarrow{F1} F2 \downarrow L1 \xrightarrow{F3} \xrightarrow{F1} F2$	L1	3.70	4.30	0.146	0.169		
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	L2	18.30	19.13	0.720	0.753		
F(x3) → → M J E	L3	14.20	20.30	0.559	0.799		
$F(x3) \downarrow \qquad M \downarrow \downarrow E \qquad G$	L4	34.05	41.38	1.341	1.629		
	L5	5.35	6.30	0.211	0.248		
	М	2.00	3.00	0.079	0.118		
	V	5° .	typ.	<b>5</b> ° 1	typ.		
	V2	60°	typ.	60°	typ.		
	Dia.	3.55	3.65	0.140	0.144		

## **3** Ordering information

### Table 6.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode	
STPS60SM200CW	STPS60SM200CW	TO-247	4.45 g	30	Tube	

## 4 Revision history

### Table 7.Document revision history

Date	Revision	Changes
17-May-2011	1	First issue.



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